

## Optoelectronic Device Notes

Reference: Scherz & Monk *Practical Electronics for Inventors*

	3 <sup>rd</sup> Edition	4 <sup>th</sup> Edition
LED Specifications	Table 5.1, Page 503 & 504	Table 5.1, Page 503
LED Wavelengths	Figure 5.9, Page 504	Figure 5.9, Page 504
LED Applications	Figure 5.10, Page 505	Figure 5.10, Page 505

### **Photoresistor** (light controlled variable resistor)

Visible spectrum - cadmium sulfide

IR spectrum - lead sulfide

Incoming photons disrupt crystalline structure and free up electrons which increases current flow

"Dark" Mega Ohms

"Light" 300 Ohms

Circuits require DC voltage source

Time delays (wavelength dependent)

    milliseconds reaction time to incoming energy

    seconds delay to return to dark state

Examples: light meter, light sensitive voltage divider

### **Photodiode** (generate current - very linear wrt light intensity / current)

"Photo-Voltaic" (current source)

"Photo-Conductive" (similar to photoresistors)

Small surface area provide fast response - good for detecting pulses of energy

Large area, more current, slower response times

Solar Cells - large capacity photodiodes (typical values 0.5 V @ 0.1 A)

    Connected in series - increases voltage

    Connected in parallel - increases current

### **Phototransistor** - light sensitive gates which can be used to control current flow

### **Thyristor** - fast acting electronic switches ( four layered PNP diodes with 2 to 4 leads)

2 lead - forward conducting (specified DC voltage)

2 lead - **DIAC** Diode for Alternating Current

3 lead - **SCR** Silicon Controlled Rectifier

    requires only very small gate current to turn on

    after being tripped, remains turned on

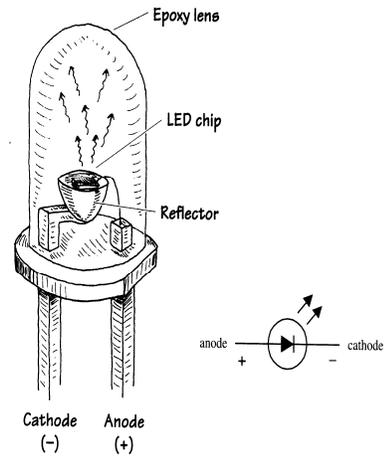
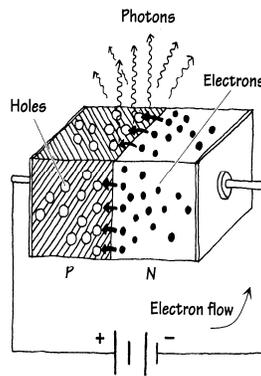
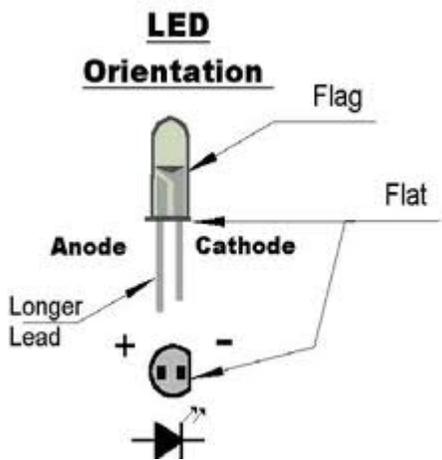
3 lead - **TRIAC** Triode for Alternating Current

    current flows in both directions when gate voltage is exceeded

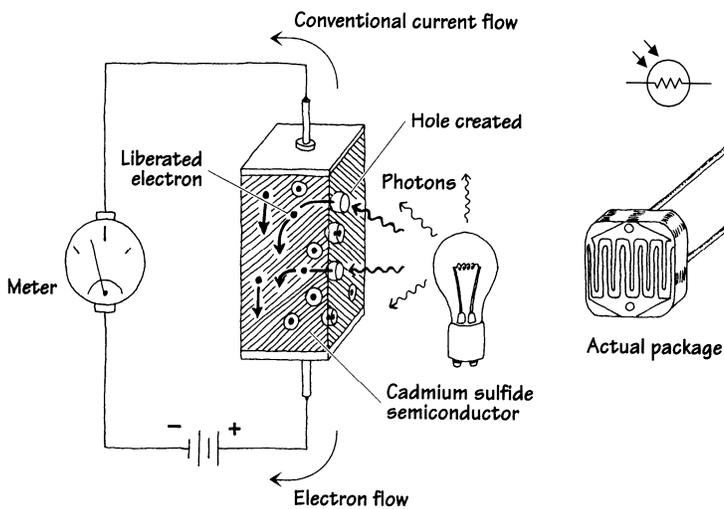
4 lead - **SCS** Silicon Controlled Switch

    turned off by applying positive voltage to anode gate

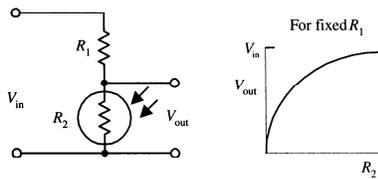
# Light Emitting Diode LED



# PhotoResistor

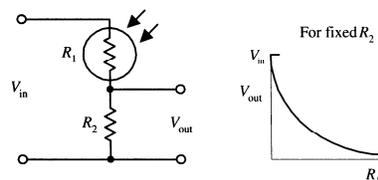


## Light-Sensitive Voltage Divider

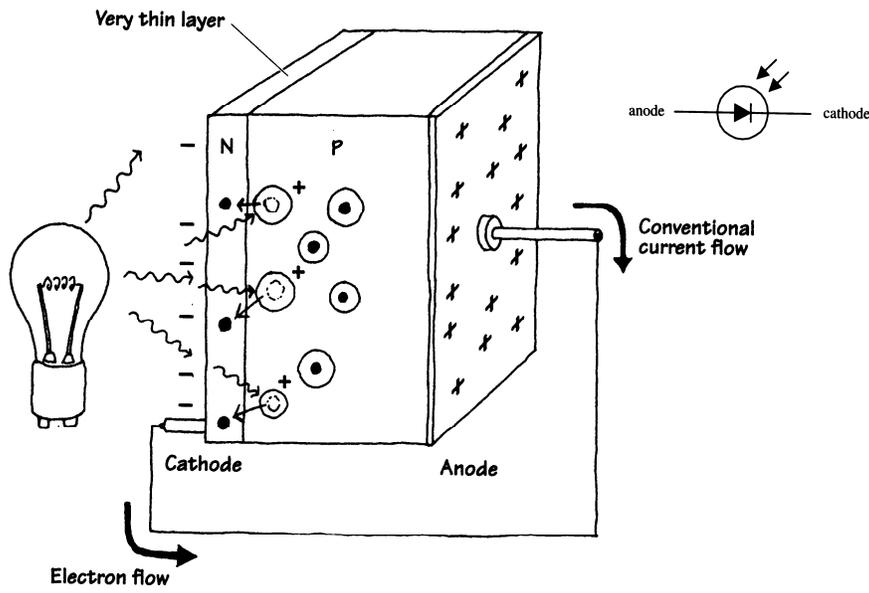


$$V_{out} = \frac{R_2}{R_1 + R_2} V_{in}$$

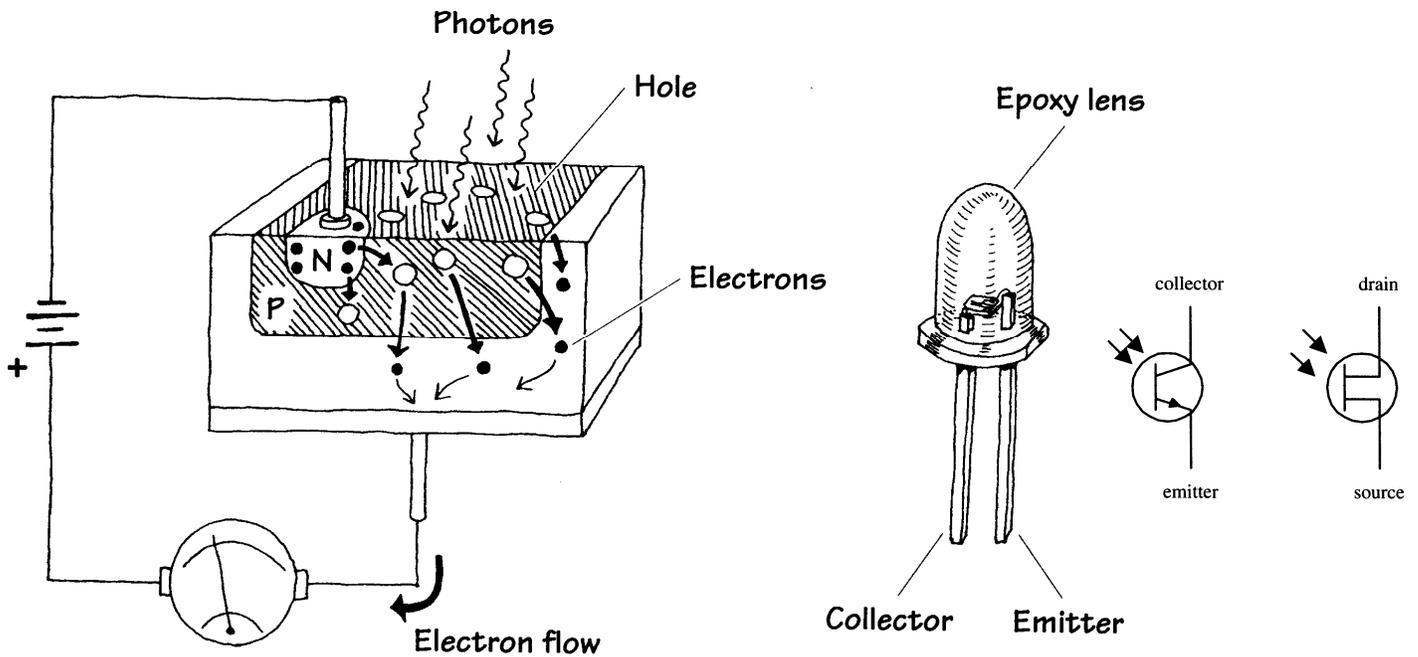
As the intensity of light increases, the resistance of the photoresistor decreases, so  $V_{out}$  in the top circuit gets smaller as more light hits it, whereas  $V_{out}$  in the lower circuit gets larger.



# PhotoDiode

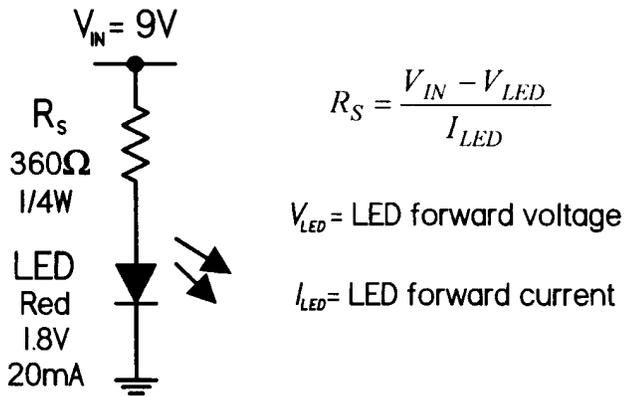


# PhotoTransistors

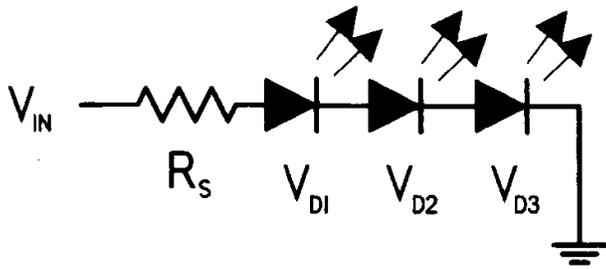


Source: Scherz, Practical Electronics for Inventors, 2nd & 3rd Editions

### LED Current Limiting

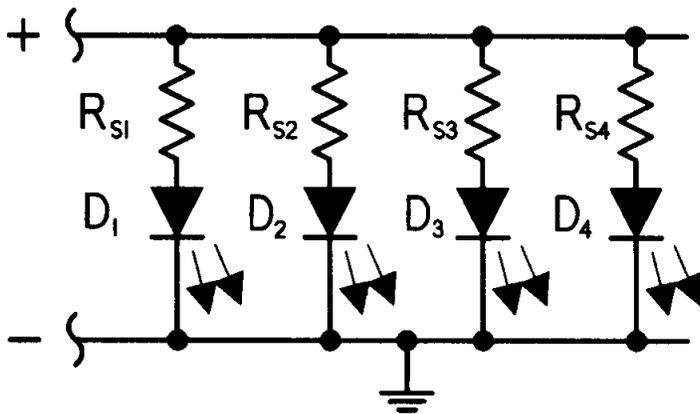


### LEDs in Series

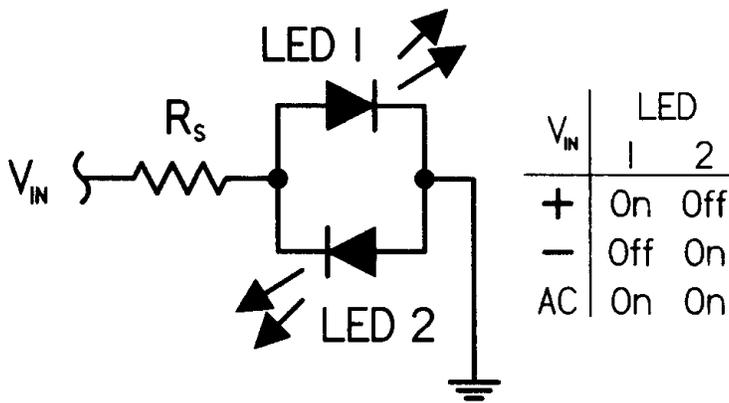


$$R_S = \frac{V_{IN} - (V_{D1} + V_{D2} + V_{D3})}{I_{D,max}}$$

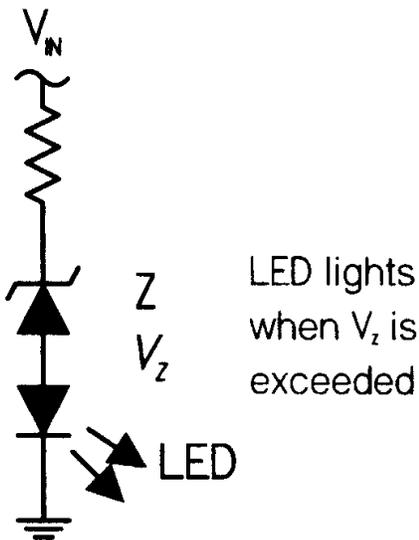
### LEDs in Parallel



## AC-DC Polarity Indicator



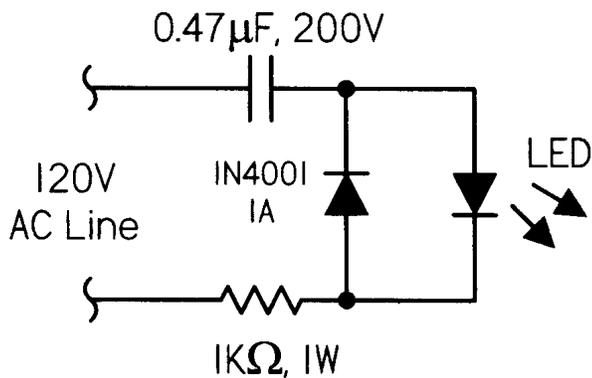
## Voltage-Level Indicator



$$R_S = \frac{V_{In} - [V_Z + V_{LED}]}{I_{LED}}$$

$$V_{In(\text{Minimum})} = R_S I_{LED} + V_Z + V_{LED}$$

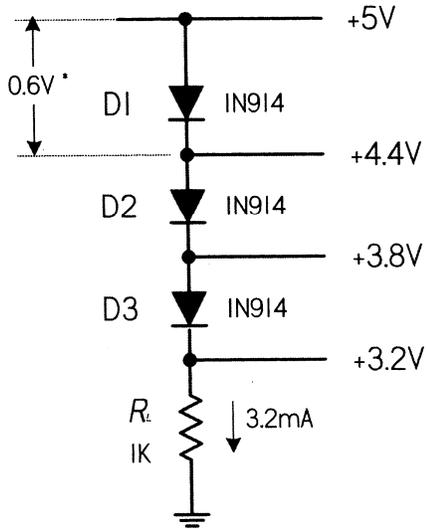
## Driving LEDs from 120VAC



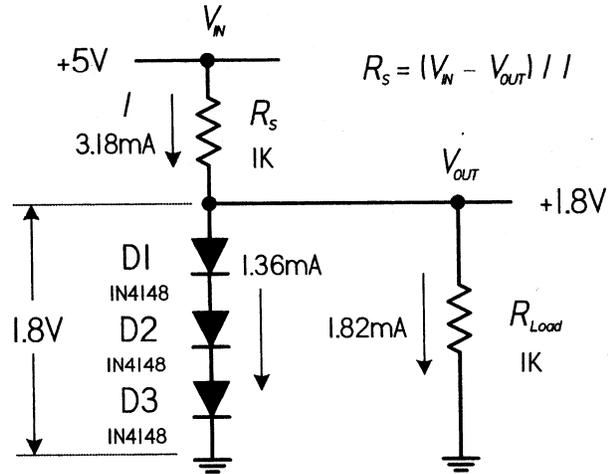
Reference: Scherz, Practical Electronics for Inventors, 2nd & 3rd Editions

### Voltage Dropper

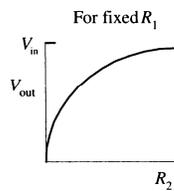
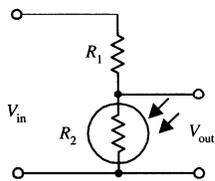
DC application



### Voltage Regulator

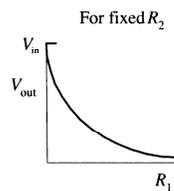
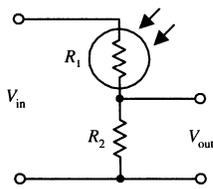


### Light-Sensitive Voltage Divider



$$V_{out} = \frac{R_2}{R_1 + R_2} V_{in}$$

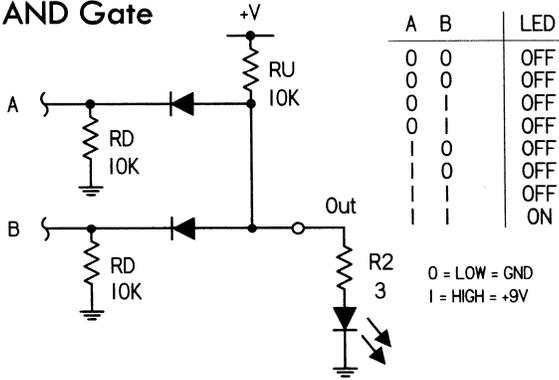
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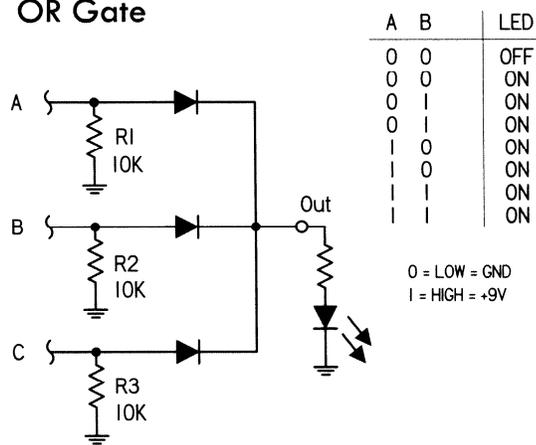
# Diode Logic Gates

## Diode Logic Gates

### AND Gate

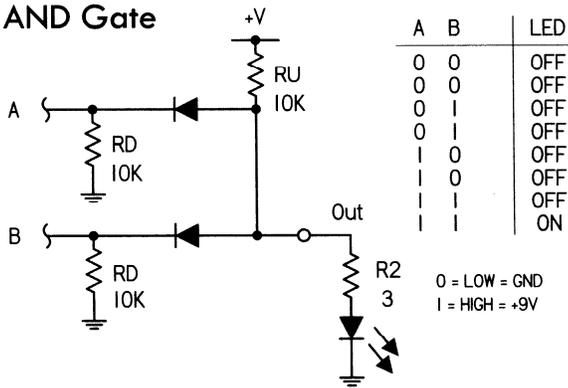


### OR Gate



## Diode Logic Gates

### AND Gate



## Diode Logic Gates

### OR Gate

